

EAST Search History

EAST Search History (Prior Art)

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	4	(("5508209") or ("5576231")).PN.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT	OR	OFF	2009/10/30 17:43
L3	0	2 and (anodized anodizing anodization electrolytic electrolyte) same (pore hole aperture micropor\$4 foraminous) and (transistor gate drain) and insulat\$4 and (semiconductor superconductor magnetic carbon) and alumin\$4	US-PGPUB; USPAT; FPRS; EPO	OR	ON	2009/10/30 17:46
S1	16	"10574186" "10599127" "60042411" "60731783" "11850668" "60824465" "29155461" "11464590" "11465303" "11557151" "11610432" "12239694" "60749997" "60862803" "60946251" "60985328" "61094297" "10574186"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/16 09:37
S2	4533	(29/592,1,599,601).OCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/04/16 12:32

S3	1153	\$2 and alumin\$4	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/16 12:55
S4	468	"1745175" "1900018" "439457" "2524035" "2569347"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/16 13:03
S5	1035955	transistor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/16 13:13
S6	1815417	\$2 and transistor or gate or drain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/16 13:36
S7	319	\$2 and (transistor or gate or drain)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/16 13:37
S8	1344516	pore hole aperture	USPAT	OR	ON	2009/04/16 14:41
S9	1850187	active carbon superconductor semiconductor magnet\$2 smart	USPAT	OR	ON	2009/04/16 14:41

S10	131421	anodiz\$3 anodization electrolyt\$4	USPAT	OR	ON	2009/04/16 14:43
S11	723762	alumin\$4	USPAT	OR	ON	2009/04/16 14:44
S12	1781315	transistor source drain gate	USPAT	OR	ON	2009/04/16 14:44
S13	444341	S9 same S12	USPAT	OR	ON	2009/04/16 14:46
S14	18630	S8 same S10	USPAT	OR	ON	2009/04/16 14:47
S15	3913	S14 and S13	USPAT	OR	ON	2009/04/16 14:47
S16	2699	S11 and S15	USPAT	OR	ON	2009/04/16 14:48
S17	313	transistor and pore and anodiz\$4	USPAT	OR	ON	2009/04/16 14:58
S18	199	(977/890).CCLS.	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/04/20 09:53
S20	173	2006/0046602 11/167,067 10/747,438 9/178,680 11/162,548 "6325909" 11/466,217 10/301,715 11/119,531 10/033,032 10/336,236	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/20 11:30

S21	40	(10/033032 10/301715 10/336236 10/394435 10/747438 10/824678 10/824679 10/824706 10/829660 10/863972 10/864045 10/864186 10/864572 10/864681 10/864682 10/864751 10/887860 10/917606 10/917794 10/917893 10/917932 10/918085 10/918181 10/935994 10/936119 10/967858 11/018370 11/032823 11/032983 11/033087 11/033089 11/033213 11/033215 11/033216 11/048231 11/053135 11/119531 11/162548 11/167067 11/188678 11/197196 11/213830 11/227468 11/280786 11/338512 11/338513 11/449969 11/466893 11/497797 11/527127 11/541834 11/542524 11/602795 11/643688 11/651177 11/653673 11/656253 11/731946 11/742290 11/835583 11/835612 11/835613 11/835651 11/835759 11/835845 11/835852 11/835856 11/835865 11/860929 11/870872 11/870897 11/892251 11/928538 11/928651 11/929076 11/945710 11/971476 12/023867 12/029118 12/029661 12/046855 12/114540 12/195675 12/202737 12/246009).APP.	USPAT; USOCR	OR	ON	2009/04/20 11:32
S22	133	S20 not S21	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/20 11:33

S23	47	S22 and pore	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/20 11:41
S24	18	((AAO or alumina or (anodi\$4 same aluminum)) with ((carbon and (nano\$1tube or nanotube)) and (transistor or FET)))	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/20 13:06
S25	0	("2007/0001220").URPN.	USPAT	OR	ON	2009/04/20 13:49
S26	19	"20020130311" "20060292870" "6740910"	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/21 09:32
S27	13447	((427/245,247,458,469,126.3) or (205/75,149,150,112) or (29/846,896.6,825,830,831,850)).CCLS.	US_PGPUB; USPAT; FPRS; EPO; JPO; DERWENT	OR	OFF	2009/10/29 14:19
S28	1346	((427/245) or (205/112) or (29/896.6)).CCLS.	US_PGPUB; USPAT; FPRS; EPO; JPO; DERWENT	OR	OFF	2009/10/29 14:20
S29	70	S28 and (anodized anodizing anodization electrolytic electrolyte) same (pore hole aperture micropor\$4 foraminous)	US_PGPUB; USPAT; FPRS; EPO	OR	ON	2009/10/29 15:19
S30	382204	"257".clas. "438".clas. "977".clas.	US_PGPUB; USPAT; FPRS; EPO	OR	ON	2009/10/29 15:36

S31	5191	S30 and (anodized anodizing anodization electrolytic electrolyte) same (pore hole aperture micropor\$4 foraminous)	US-PGPUB; USPAT; FPRS; EPO	OR	ON	2009/10/29 15:37
S32	2	"20060011972"	US-PGPUB; USPAT; FPRS; EPO	OR	ON	2009/10/29 15:37
S33	2280	S30 and (anodized anodizing anodization electrolytic electrolyte) same (pore hole aperture micropor\$4 foraminous) and (transistor gate drain)	US-PGPUB; USPAT; FPRS; EPO	OR	ON	2009/10/29 15:38
S34	1980	S30 and (anodized anodizing anodization electrolytic electrolyte) same (pore hole aperture micropor\$4 foraminous) and (transistor gate drain) and insulat\$4 and (semiconductor superconductor magnetic carbon)	US-PGPUB; USPAT; FPRS; EPO	OR	ON	2009/10/29 15:39
S35	1	"20030132461"	US-PGPUB; USPAT; FPRS; EPO	OR	ON	2009/10/29 15:40
S36	1497	S30 and (anodized anodizing anodization electrolytic electrolyte) same (pore hole aperture micropor\$4 foraminous) and (transistor gate drain) and insulat\$4 and (semiconductor superconductor magnetic carbon) and alumin\$4	US-PGPUB; USPAT; FPRS; EPO	OR	ON	2009/10/29 15:49
S37	6	("4501663" "4687551" "5112449").PN. OR ("5259957").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2009/10/29 15:50
S38	58	S28 and (anodized anodizing anodization electrolytic electrolyte) same (pore hole aperture micropor\$4 foraminous) same (form\$4 creat\$4)	US-PGPUB; USPAT; FPRS; EPO	OR	ON	2009/10/29 16:09

S39	19	S28 and (anodized anodizing anodization electrolytic electrolyte) same (pore hole aperture microporous\$4 foraminous) same (second direction)	US-PGPUB; USPAT; FPRS; EPO	OR	ON	2009/10/29 16:17
S40	13	("3850762").PN. OR ("4687551").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2009/10/29 16:33
S41	6	("4501663" "4687551" "5112449").PN. OR ("5259957").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2009/10/29 16:36

EAST Search History (Interference)

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10/30/2009 5:50:24 PM

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